

FDMS4435BZ

October 2014

P-Channel PowerTrench® MOSFET -30 V, -18 A, 20 m Ω

Features

- Max $r_{DS(on)} = 20 \text{ m}\Omega$ at $V_{GS} = -10 \text{ V}$, $I_D = -9.0 \text{ A}$
- Max $r_{DS(on)}$ = 37 m Ω at V_{GS} = -4.5 V, I_D = -6.5 A
- Extended V_{GSS} range (-25 V) for battery applications
- High performance trench technology for extremely low r_{DS(on)}
- High power and current handling capability
- HBM ESD protection level >7 kV typical (Note 4)
- 100% UIL tested
- Termination is Lead-free and RoHS Compliant

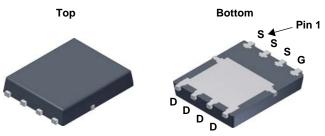


General Description

This P-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench® process that has been especially tailored to minimize the on-state resistance. This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.

Applications

- High side in DC-DC Buck Converters
- Notebook battery power management
- Load switch in Notebook



Power 56

D 5 4 G D 6 3 S D 7 2 S D 8 1 S

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DS}	Drain to Source Voltage			-30	V
V_{GS}	Gate to Source Voltage			±25	V
	Drain Current -Continuous (Package limited)	T _C = 25 °C		-18	
	-Continuous (Silicon limited)	T _C = 25 °C		-35	_
ID	-Continuous	T _A = 25 °C	(Note 1a)	-9.0	Α
	-Pulsed			-50	
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	18	mJ
В	Power Dissipation	T _C = 25 °C		39	W
P_{D}	Power Dissipation	T _A = 25 °C	(Note 1a)	2.5	VV
T _J , T _{STG}	Operating and Storage Junction Temperature R	ange		-55 to +150	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	3.2	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	50	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS4435BZ	FDMS4435BZ	Power 56	13 "	12 mm	3000 units

Electrical Characteristics $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	rest Conditions	IVIII	тур	IVIAX	Units
Off Chara	acteristics					
BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = -250 \mu A, V_{GS} = 0 V$	-30			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I_D = -250 μ A, referenced to 25 °C		-23		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = -24 V, V _{GS} = 0 V			-1	μΑ
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μΑ

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = -250 \mu A$	-1.0	-1.9	-3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = -250 μ A, referenced to 25 °C		6		mV/°C
		$V_{GS} = -10 \text{ V}, I_D = -9.0 \text{ A}$		15	20	
r	Static Drain to Source On Resistance	$V_{GS} = -4.5 \text{ V}, I_D = -6.5 \text{ A}$		22	37	mΩ
r _{DS(on)} Static Drain to Source On Resistance	$V_{GS} = -10 \text{ V}, I_D = -9.0 \text{ A}$ $T_J = 125 ^{\circ}\text{C}$		21	28	11122	
9 _{FS}	Forward Transconductance	$V_{DS} = -5 \text{ V}, I_{D} = -9.0 \text{ A}$		25		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V 45 V V 0 V	1540	2050	pF
C _{oss}	Output Capacitance	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1 MHz	290	390	pF
C _{rss}	Reverse Transfer Capacitance	1 = 1 101112	260	385	pF
R _a	Gate Resistance		5		Ω

Switching Characteristics

t _{d(on)}	Turn-On Delay Time		9	17	ns
t _r	Rise Time	V _{DD} = -15 V, I _D = -9.0 A,	10	18	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = -10 \text{ V}, R_{GEN} = 6 \Omega$	35	56	ns
t _f	Fall Time		19	33	ns
Q_g	Total Gate Charge	V _{GS} = 0 V to -10 V	34	47	nC
Q_g	Total Gate Charge	$V_{GS} = 0 \text{ V to -4.5 V} V_{DD} = -15 \text{ V},$	18	25	nC
Q_{gs}	Gate to Source Charge	I _D = -9.0 A	5		nC
Q _{gd}	Gate to Drain "Miller" Charge		9		nC

Drain-Source Diode Characteristics

V	Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = -1.9 \text{ A}$ (Note	2)	0.75	1.2	V
v _{SD}	Source to Drain blode i ofward voltage	$V_{GS} = 0 \text{ V}, I_S = -9.0 \text{ A}$ (Note	2)	0.86	1.5	V
t _{rr}	Reverse Recovery Time	- I _E = -9.0 A, di/dt = 100 A/μs		25	39	ns
Q _{rr}	Reverse Recovery Charge	- I _F = -9.0 A, α//αt = 100 A/μs		12	21	nC

^{1.} R_{0,JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0,JC} is guaranteed by design while R_{0,CA} is determined by the user's board design.



 a) 50 °C/W when mounted on a 1 in² pad of 2 oz copper



b) 125 °C/W when mounted on a minimum pad of 2 oz copper.

^{2.} Pulse Test: Pulse Width < 300 $\mu\text{s},$ Duty cycle < 2.0%.

^{3.} E_{AS} of 18 mJ is based on starting T_J = 25 °C, L = 1 mH, I_{AS} = -6 A, V_{DD} = -27 V, V_{GS} = -10 V. 100% tested at L = 0.3 mH, I_{AS} = -8 A.

^{4.} The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

Typical Characteristics T_J = 25 °C unless otherwise noted

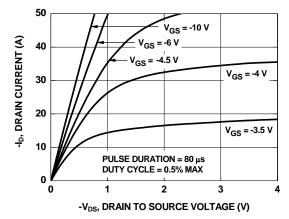


Figure 1. On-Region Characteristics

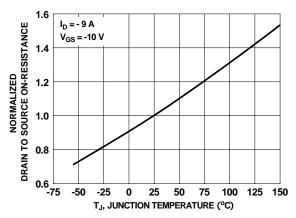


Figure 3. Normalized On-Resistance vs Junction Temperature

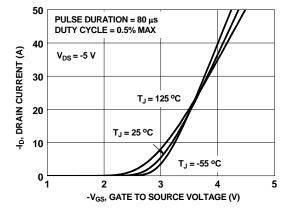


Figure 5. Transfer Characteristics

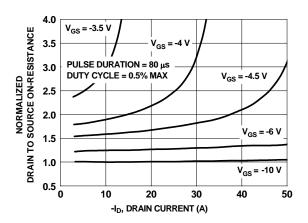


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

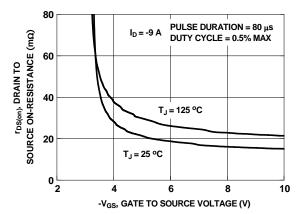


Figure 4. On-Resistance vs Gate to Source Voltage

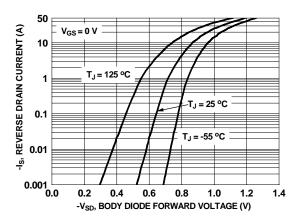


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25$ °C unless otherwise noted

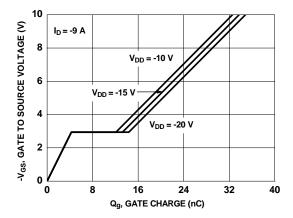


Figure 7. Gate Charge Characteristics

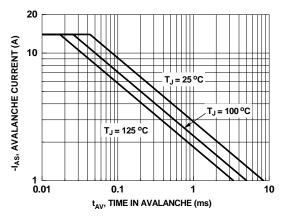


Figure 9. Unclamped Inductive Switching Capability

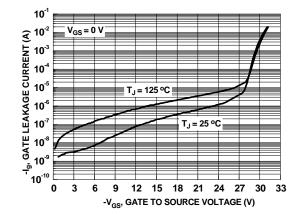


Figure 11. Gate Leakage Current vs Gate to Source Voltage

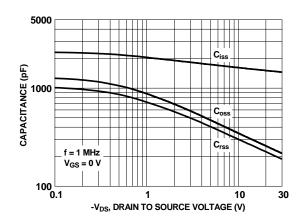


Figure 8. Capacitance vs Drain to Source Voltage

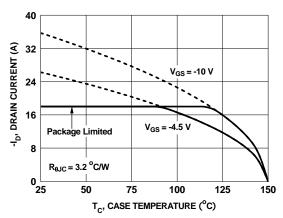


Figure 10. Maximum Continuous Drain Current vs Cate Temperature

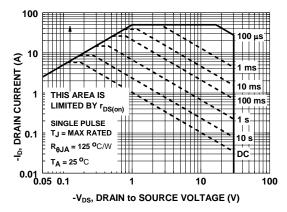


Figure 12. Forward Bias Safe Operating Area

Typical Characteristics $T_J = 25$ °C unless otherwise noted

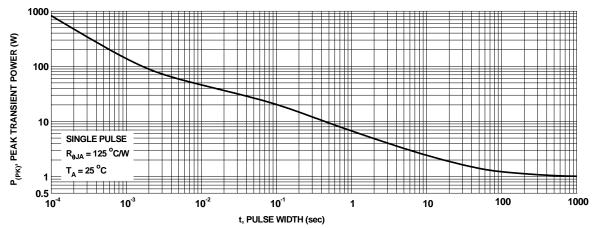


Figure 13. Single Pulse Maximum Power Dissipation

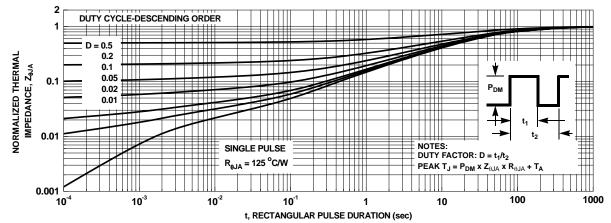
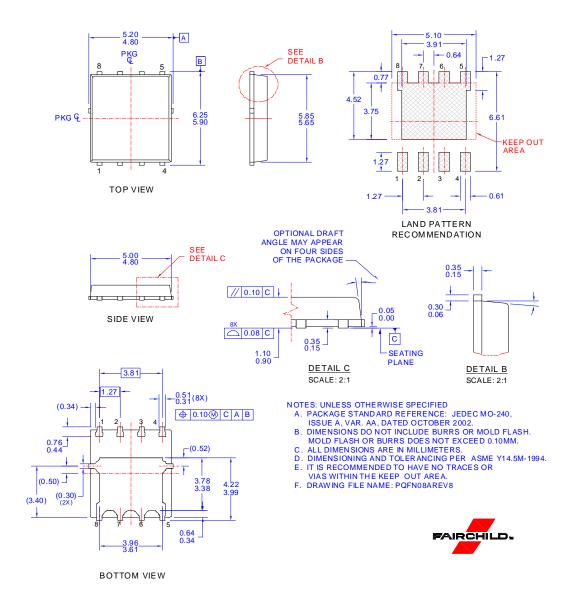


Figure 14. Junction-to-Ambient Transient Thermal Response Curve

Dimensional Outline and Pad Layout



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